

# Study of photoexcited-carrier dynamics in GaAs photoconductive switches using dynamic terahertz emission microscopy: publisher's note

Hironaru Murakami,\* Shogo Fujiwara, Iwao Kawayama, and Masayoshi Tonouchi

*Institute of Laser Engineering, Osaka University, 2-6 Yamadaoka, Suita, Osaka 565-0871, Japan*

*\*Corresponding author: hiro@ile.osaka-u.ac.jp*

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The article [1] was corrected online as of 25 August 2016.

## REFERENCE

1. H. Murakami, S. Fujiwara, I. Kawayama, and M. Tonouchi, "Study of photoexcited-carrier dynamics in GaAs photoconductive switches using dynamic terahertz emission microscopy," *Photon. Res.* **4**, A9–A15 (2016).